

### Features

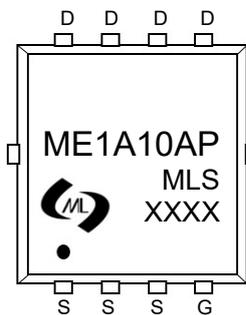
- Low  $R_{DS(on)}$  & FOM
- Extremely low switching loss
- Excellent stability and uniformity

### Product Summary

$V_{DS}$	$R_{DS(ON)}$ MAX	$I_D$ MAX
-100V	200m $\Omega$ @-10V	-10A
	250m $\Omega$ @-4.5V	

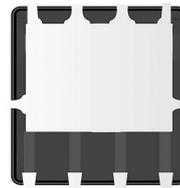
### Application

- Power management
- Portable equipment

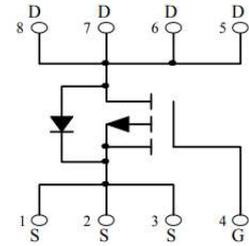


ME1A10AP: Device code  
 XXXX : Code

Marking and pin assignment



PDFN3X3-8L view



Schematic diagram



Halogen-Free

### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
--------	-----------	--------	------

### Common Ratings (TC=25°C Unless Otherwise Noted)

$V_{DS}$	Drain-Source Breakdown Voltage	-100	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$T_J$	Maximum Junction Temperature	150	°C
$T_{STG}$	Storage Temperature Range	-50 to 155	°C
$I_S$	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$ -10	A

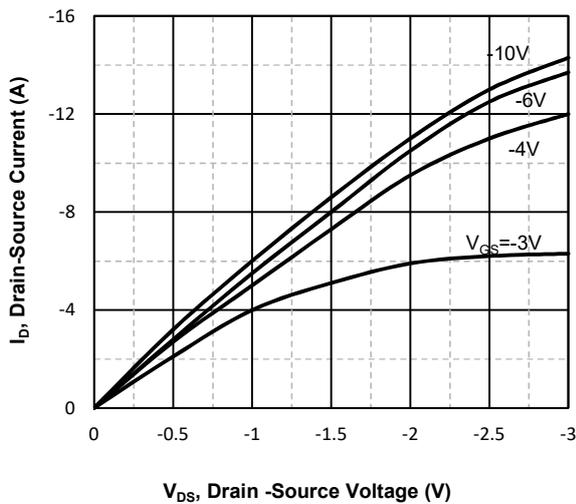
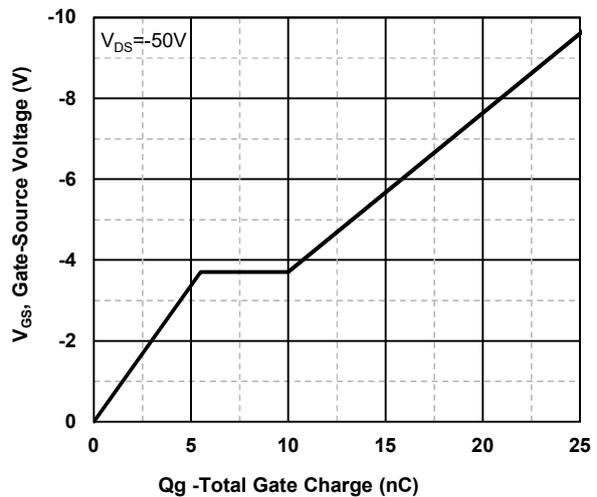
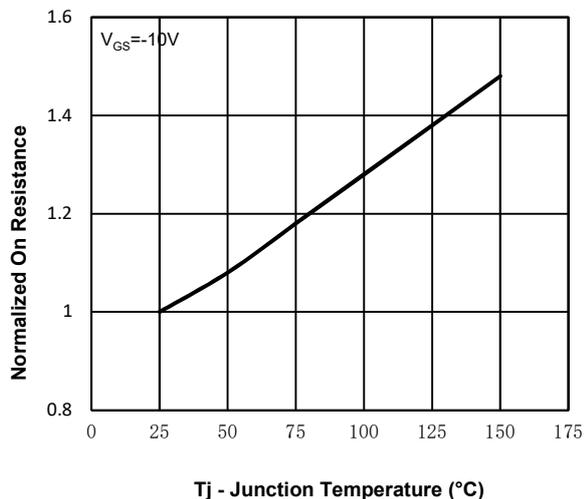
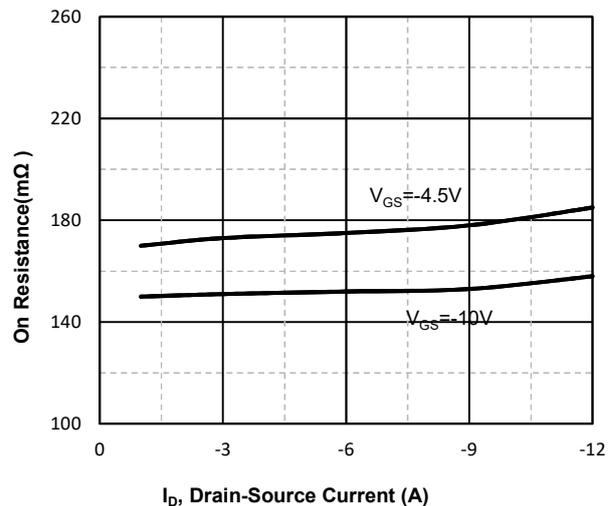
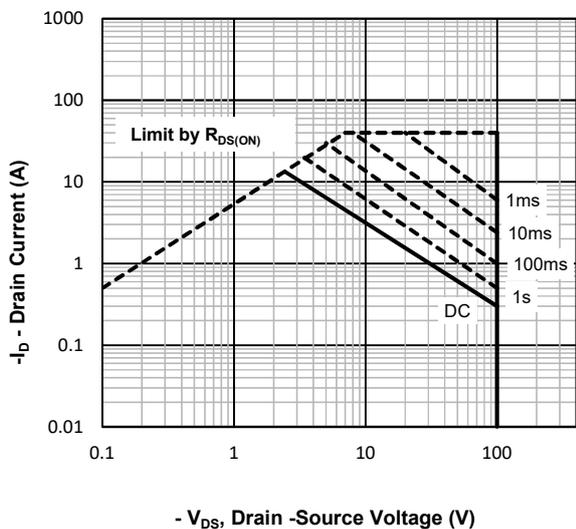
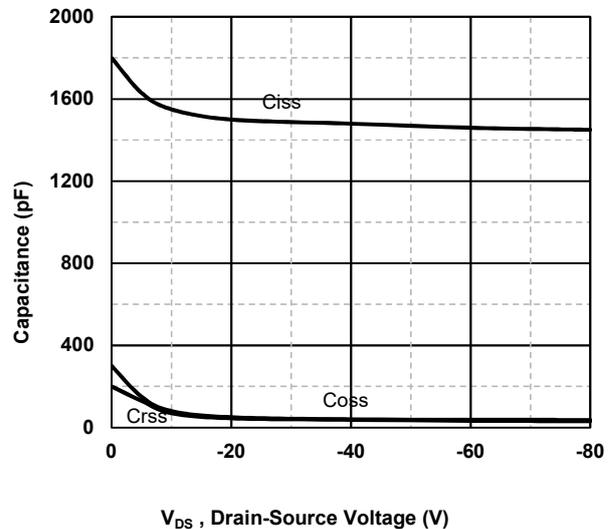
### Mounted on Large Heat Sink

$I_{DM}$	Pulse Drain Current Tested	$T_c=25^\circ\text{C}$ -40	A
$I_D$	Continuous Drain Current	$T_c=25^\circ\text{C}$ -10	A
$P_D$	Maximum Power Dissipation	$T_c=25^\circ\text{C}$ 1.8	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	315	°C/W

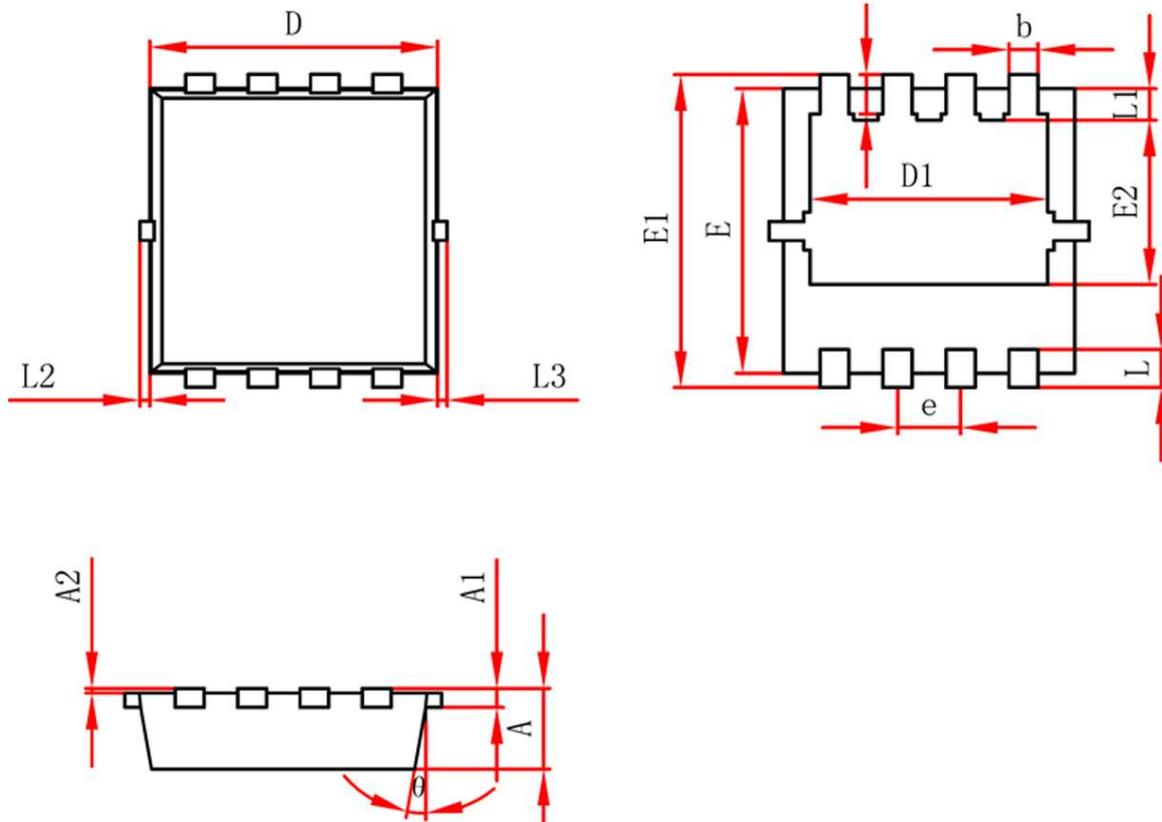
### Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
ME1A10AP	PDFN3X3-8L	ME1A10AP	5,000	10,000	70,000	13"reel

Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-100	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-100V, V <sub>GS</sub> =0V	--	--	-1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.0	-1.8	-3.0	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =-10V, I <sub>D</sub> =-10A	--	155	200	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-5A	--	170	250	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =-50V, V <sub>GS</sub> =0V, f=1MHz	--	1488	--	pF
C <sub>OSS</sub>	Output Capacitance		--	39	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	30	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =-50V, I <sub>D</sub> =-10A, V <sub>GS</sub> =-10V	--	26.5	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	6	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	4	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DS</sub> =-50V, I <sub>D</sub> =-10A, V <sub>GS</sub> =-10V, R <sub>G</sub> =4.5Ω	--	14	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	45	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	227	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	93	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =-10A	--	-0.8	-1.2	V

**Typical Operating Characteristics**

**Fig1. Typical Output Characteristics**

**Fig2. Typical Gate Charge Vs. Gate-Source Voltage**

**Fig3. Normalized On-Resistance Vs. Temperature**

**Fig4. On-Resistance Vs. Drain-Source Current**

**Fig5. Maximum Safe Operating Area**

**Fig6. Typical Capacitance Vs. Drain-Source Voltage**

## PDFN3X3-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.750	0.850	0.030	0.034
A1	0.152 REF.		0.006 REF.	
A2	0~0.05		0~0.002	
D	2.950	3.150	0.117	0.125
D1	2.400	2.500	0.095	0.099
E	2.950	3.050	0.117	0.121
E1	3.250	3.350	0.129	0.132
E2	1.685	1.785	0.067	0.071
b	0.250	0.350	0.010	0.014
e	0.600	0.700	0.024	0.028
L	0.350	0.450	0.014	0.018
L1	0.325	0.425	0.013	0.017
L2	0~0.100		0~0.004	
L3	0~0.100		0~0.004	
H	0.365	0.465	0.014	0.018
θ	10°	12°	10°	12°